

EAST Search History

EAST Search History (Prior Art)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	18666	(LDMOS\$2 or LD-MOS\$2 or (LD adj MOS\$3) or LDMOSFET\$1 or LD-MOSFET\$1 or (LD adj MOSFET\$1)) or (lateral\$4 adj diffus\$5 adj metal adj oxide adj semiconduct\$4) or (lateral\$4 adj diffus\$5 adj (MOS\$3 or MOSFET\$1)) or (LDDMOS\$2 or LDD-MOS\$2 or (LDD adj MOS\$3) or LDDMOSFET\$1 or LDD-MOSFET\$1 or (LDD adj MOSFET\$1)) or (((lateral\$4 adj double adj diffus\$5 adj metal adj oxide adj semiconduct\$4) or (lateral\$4 adj double-diffus\$5 adj metal adj oxide adj semiconduct\$4)) or (lateral\$4 adj double adj diffus\$5 adj (MOS\$3 or MOSFET\$1)) or (lateral\$4 near7 (metal adj oxide adj semiconduct\$4) or (lateral\$4 near7 (MOS or MOSFET\$1 or NMOS or NMOSFET\$1 or PMOS or PMOSFET\$1)) or (LDPMOS\$2 or LD-PMOS\$2 or (LD adj PMOS\$3) or LDPMOSFET\$1 or LD-PMOSFET\$1 or (LD adj PMOSFET\$1)) or (LDNMOS\$2 or LD-NMOS\$2 or (LD adj NMOS\$3) or LDNMOSFET\$1 or LD-NMOSFET\$1 or (LD adj NMOSFET\$1)) or (lateral\$4 near7 (DMOS or DMOSFET\$1)) or (lateral\$4 adj8 (MOS or MOSFET\$1 or NMOS or NMOSFET\$1 or PMOS or PMOSFET\$1 or FET\$1 or transistor\$1 or IGFET\$1 or (insulat\$5 adj gate adj field adj effect adj transistor\$1))))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:07

L2	3242700	gate\$1 or electrode\$1	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:11
L3	843756	((field adj (oxide\$1 or isolat \$5)) or LOCOSS\$2 or trench \$2 or STI\$1 or (shallow adj trench\$2 adj isolat\$5))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:11
L4	1672	implant\$8 with (silicon or Si or "Si" or Ge or "Ge" or germanium) with ((amorphous or amorph \$9) near3 (region\$1 or area\$1 or part\$1 or portion \$1 or element\$1))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:14
L5	39	diffus\$8 with (ion\$1 or dopant\$1) with channel\$3 with ((amorphous or amorph\$9) near3 (region \$1 or area\$1 or part\$1 or portion\$1 or element\$1))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:16
L6	1	1 and 2 and 3 and 4 and 5	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:16
L7	0	("2001/0049172").URPN.	USPAT	OR	OFF	2009/09/14 10:17
L8	214	diffus\$8 same (ion\$1 or dopant\$1) same channel \$3 same ((amorphous or amorph\$9) near3 (region \$1 or area\$1 or part\$1 or portion\$1 or element\$1))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:19
L9	18	8 and 1 and 2 and 3 and 4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:19
L10	13	9 and @ad <= "20010104"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:20

L11	1737	channel\$3 near8 ((amorphous or amorph \$9) near3 (region\$1 or area\$1 or part\$1 or portion \$1 or element\$1))	US-PGPUB; USPAT; USOCR; FPPS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:28
L12	9	1 and 2 and 3 and 4 and 11	US-PGPUB; USPAT; USOCR; FPPS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/09/14 10:29
L13	1	("6225154").PN.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:38
L14	2742	(438/197).CCLS.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:42
L15	791	(438/286).CCLS.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:43
L16	463	(438/291).CCLS.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:44
L17	1516	(438/301).CCLS.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:45
L18	157	(438/520).CCLS.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:46
L19	506	(438/528).CCLS.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:46
L20	565	(438/530).CCLS.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:46
L21	1642	(438/585).CCLS.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:47
L22	332	(438/542).CCLS.	US-PGPUB; USPAT	OR	OFF	2009/09/14 10:47

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